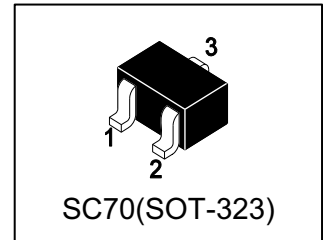


Small Signal MOSFET
380 mAmps, 60 Volts N-Channel SC-70

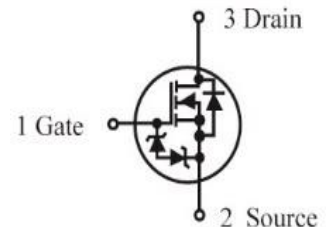
FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- ESD Protected



DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
2N7002KS3	SK	10000/Tape&Reel



MAXIMUM RATINGS(Ta = 25° C)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	VDSS	60	Vdc
Gate-Source Voltage	VGS	±20	Vdc
Drain Current	ID		mAdc
– Steady State TA = 25°C		320	
TA = 85°C		230	
– t<5s TA = 25°C		380	
TA = 85°C		270	
Pulsed Drain Current (tp=10µs)	IDM	1.5	A
Source Current (Body Diode)	IS	300	mA

THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Total Device Dissipation(Note 1)	PD		mW
– Steady State		300	
– t<5s		420	
Junction-to-Ambient(Note 1)	RθJA		°C/W
– Steady State		417	
– t<5s		300	
Lead Temperature for Soldering Purposes (1/8 " from case for 10 s)	TL	260	°C
Junction and Storage temperature	TJ,Tstg	-55~+150	°C
Gate-Source ESD Rating(HBM, Method 3015)	ESD	2000	V

1. FR-5 = 1.0×0.75×0.062 in.

ELECTRICAL CHARACTERISTICS (Ta= 25 °C)

OFF CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Drain–Source Breakdown Voltage (VGS = 0, ID = 250μAdc)	VBRDSS	60	-	-	Vdc
Drain–to–Source Breakdown Voltage Temperature Coefficient	VBRDSS/TJ	-	71	-	mV/°C
Zero Gate Voltage Drain Current (VGS = 0, VDS = 60 Vdc)	IDSS	TJ = 25°C	-	1.0	μAdc
(VGS = 0, VDS = 50 Vdc)		TJ = 125°C	-	500	
Gate–Body Leakage Current, Forward (VGS = 20 Vdc)	IGSSF	-	-	10	μAdc
Gate–Body Leakage Current, Reverse (VGS = - 20 Vdc)	IGSSR	-	-	-10	μAdc

ON CHARACTERISTICS (Note 2)

Gate Threshold Voltage (VDS = VGS, ID = 250μAdc)	VGS(th)	1.0	-	1.9	Vdc
Negative Threshold Temperature Coefficient	VGS(TH)/TJ	-	4	-	mV/°C
Static Drain–Source On–State Resistance (VGS = 10 Vdc, ID = 500 mAdc)	RDS(on)	-	-	2.3	Ω
(VGS = 5.0 Vdc, ID = 50 mAdc)		-	-	2.7	
Forward Transconductance (VDS = 5.0 Vdc, ID = 200 mAdc)	gfs	80	-	-	mS

DYNAMIC CHARACTERISTICS

Input Capacitance (VDS = 25 Vdc, VGS = 0, f = 1.0 MHz)	Ciss	-	34	-	pF
Output Capacitance (VDS = 25 Vdc, VGS = 0, f = 1.0 MHz)	Coss	-	3	-	pF
Reverse Transfer Capacitance (VDS = 25 Vdc, VGS = 0, f = 1.0 MHz)	Crss	-	2.2	-	pF

SWITCHING CHARACTERISTICS

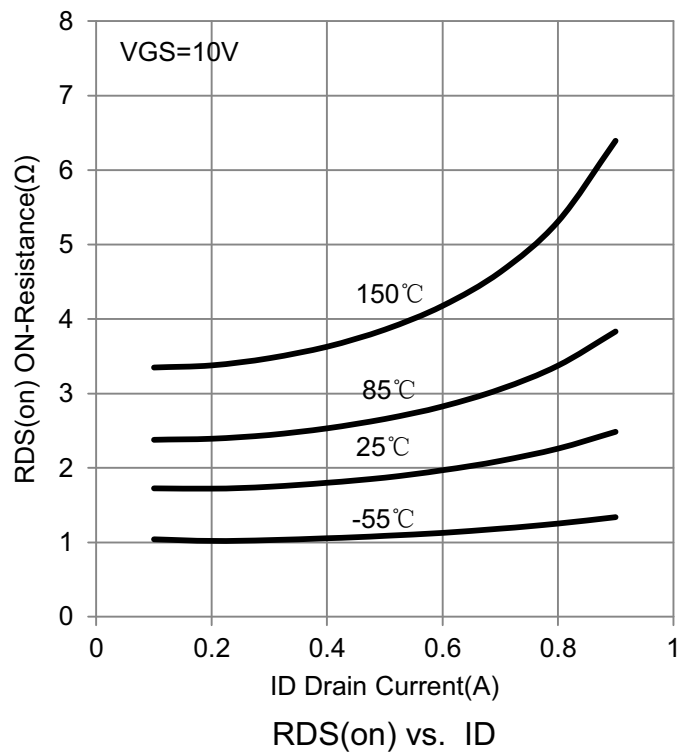
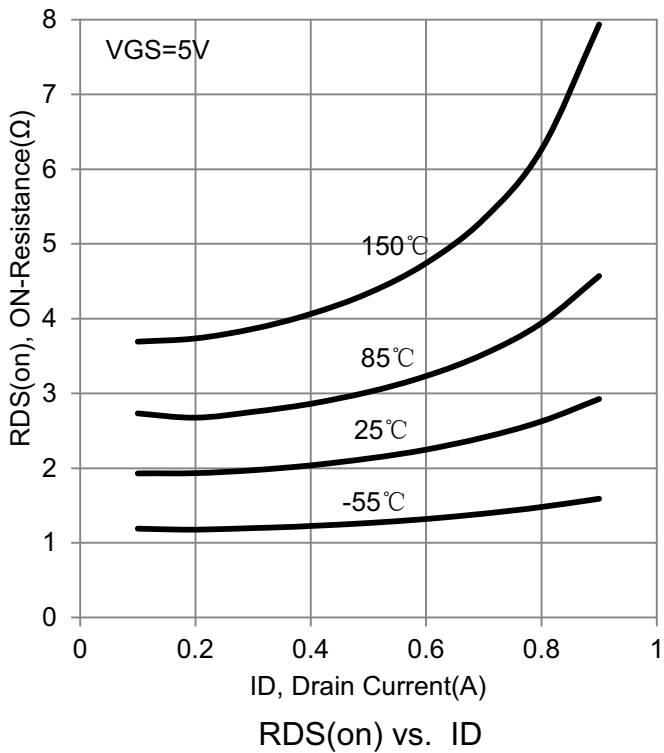
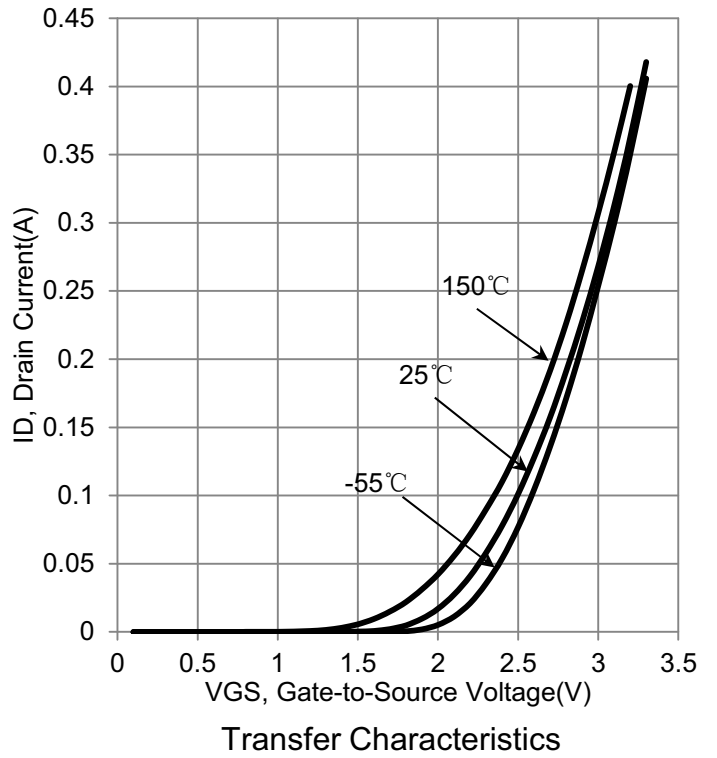
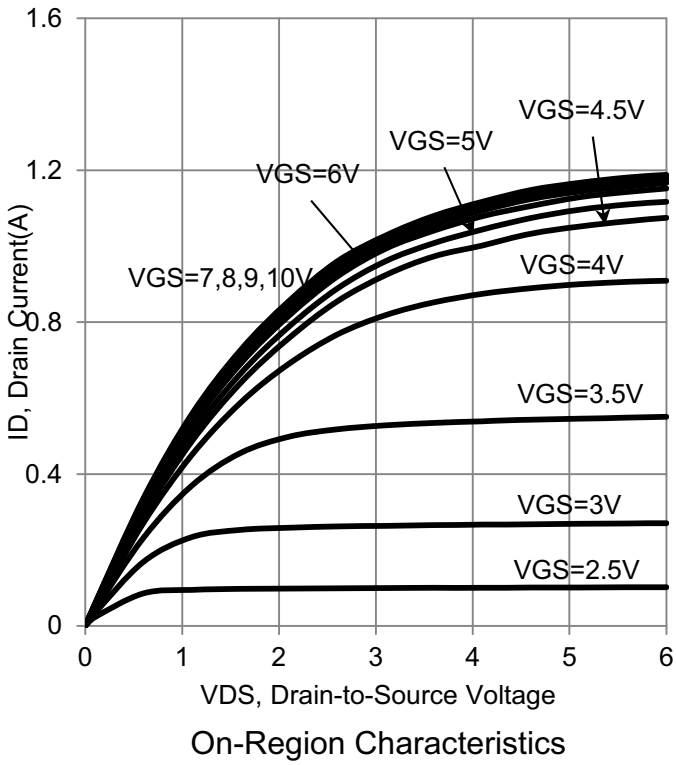
Turn-On Delay Time	VDS = 10 V, VGEN = 10 V, ID = 500 mA	td(on)	-	3.8	-	ns
Rise Time		tr	-	3.4	-	
Turn-Off Delay Time		td(off)	-	19	-	
Fall Time		tf	-	12	-	

BODY–DRAIN DIODE RATINGS

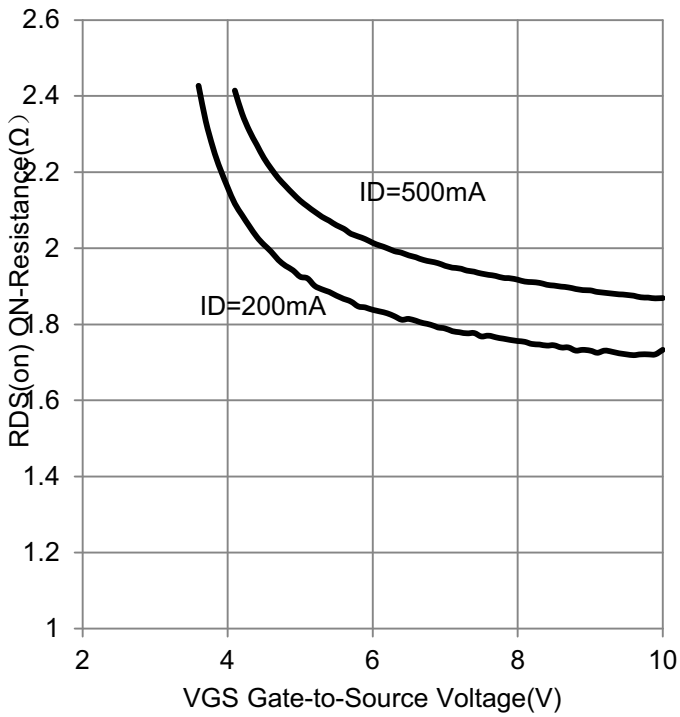
Diode Forward On–Voltage (IS = 115 mAdc, VGS = 0 V)	TJ = 25°C	VSD	-	-	1.4	Vdc
	TJ = 85°C		-	0.7	-	

2.Pulse Test: Pulse Width ≤300 μs, Duty Cycle ≤2.0%.

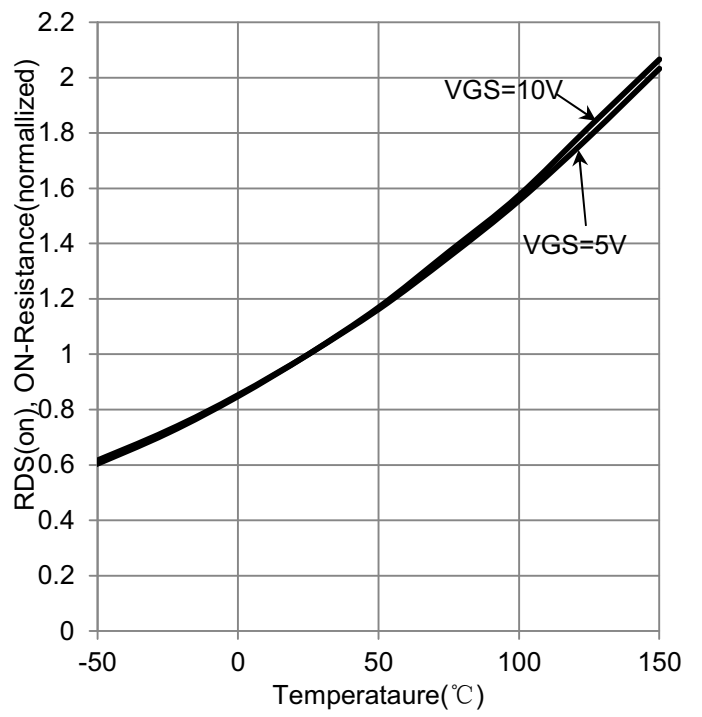
RATING AND CHARACTERISTICS CURVES (2N7002KS3)



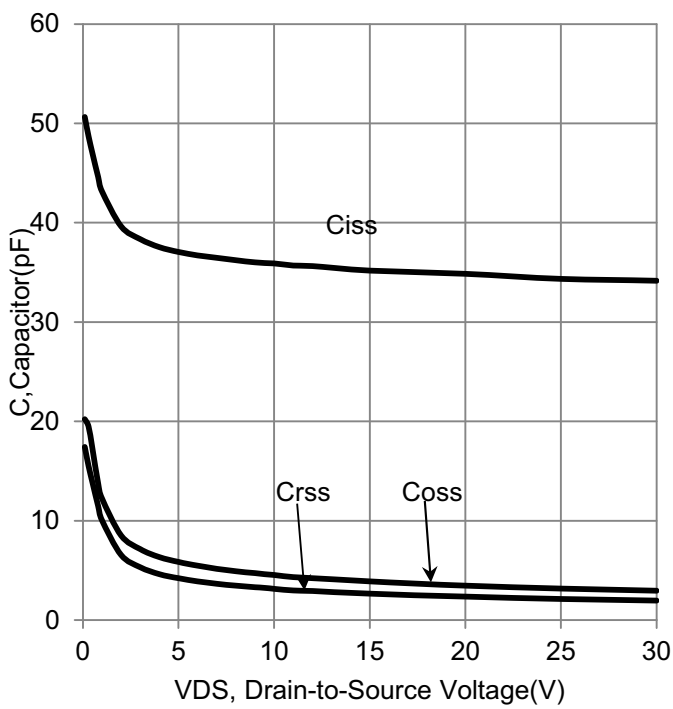
RATING AND CHARACTERISTICS CURVES (2N7002KS3)



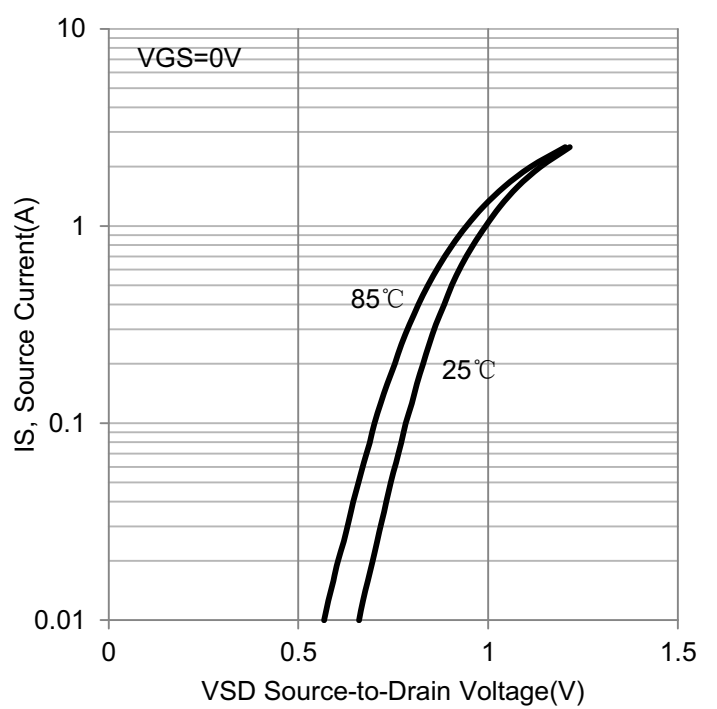
RDS(on) vs. VGS



RDS(on) vs. Temperature

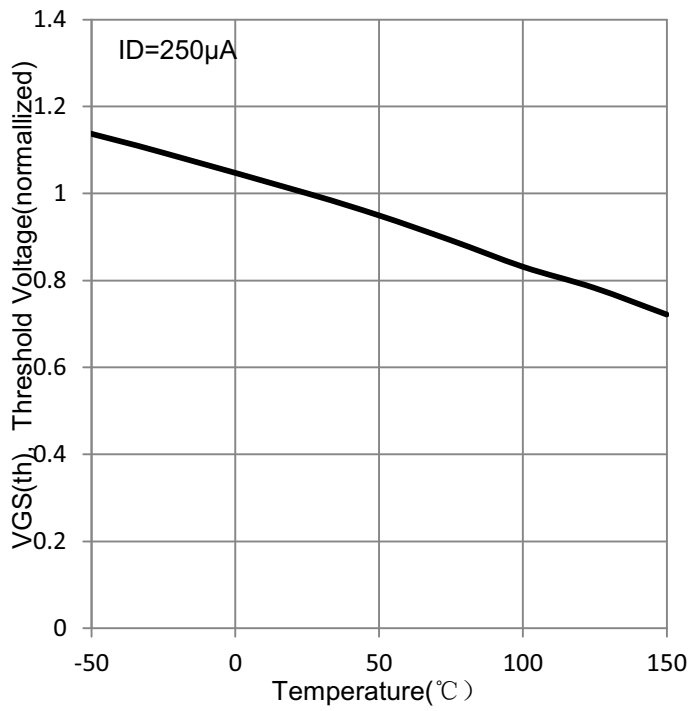


Capacitor vs. VDS



I_S vs. V_{SD}

RATING AND CHARACTERISTICS CURVES (2N7002KS3)

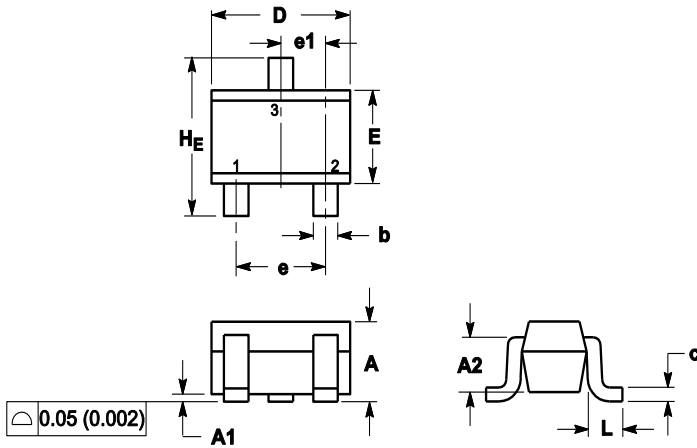


$V_{GS(th)}$ vs. Temperature

OUTLINE AND DIMENSIONS

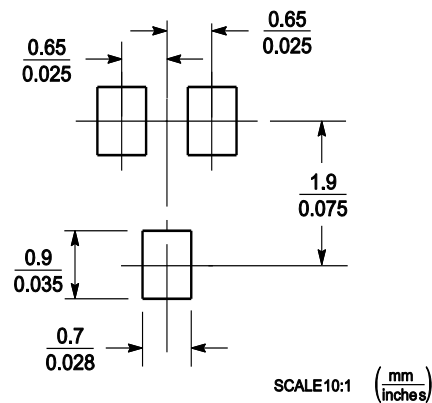
Notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.



DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.039
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70REF			0.028REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65REF			0.026REF		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

8.SOLDERING FOOTPRINT



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